National Semiconductor

DM74LS573 Octal D-Type Latch (with TRI-STATE® Outputs)

General Description

The 'LS573 is a high speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable (\overline{OE}) inputs.

This device is functionally identical to the 'LS373, but has different pinouts. For truth tables, discussion of operations and AC and DC specifications, please refer to the 'LS373 data sheet.

Features

- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- Functionally identical to 'LS373
- Input clamp diodes limit high speed termination effects
- Fully TTL and CMOS compatible



Absolute Maximum Ratings (Note) If Military/Aerospace specified devices are required,

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	7V
Operating Free Air Temperature Range	
DM74LS	0°C to +70°C
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation. LS573

Recommended Operating Conditions

Symbol	Parameter	DM74LS			Units
- Oymbol		Min	Nom	Max	onita
V _{CC}	Supply Voltage	4.75	5	5.25	v
VIH	High Level Input Voltage	2			v
VIL	Low Level Input Voltage			0.8	v
юн	High Level Input Current			-2.6	mA
IOL	Low Level Output Current			24	mA
T _A	Free Air Operating Temperature	0		70	°C

Electrical Characteristics

Over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min$, $I_{I} = -18 \text{ mA}$			-1.5	V
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max,$ $V_{IL} = Max$	2.7	3.4		v
V _{OL}	Low Level Output Voltage	$V_{CC} = Min$, $I_{OL} = Max$, $V_{IH} = Min$		0.35	0.5	v
		$I_{OL} = 4 \text{ mA}, V_{CC} = \text{Min}$		0.25	0.4	
կ	Input Current @ Max Input Voltage	$V_{CC} = Max, V_{I} = 10V$			1	mA
liH	High Level Input Current	$V_{CC} = Max, V_I = 2.7V$			20	μΑ
Ι _{ΙL}	Low Level Input Current	$V_{CC} = Max, V_1 = 0.4V$			-0.4	mA
los	Short Circuit Output Current	V _{CC} = Max (Note 2)	-30		-130	mA
Icc	Supply Current	V _{CC} = Max			50	mA
I _{OZH}	TRI-STATE Output off Current High	$V_{CC} = V_{CCH}$ $V_{OZH} = 2.7V$			20	μΑ
I _{OZL}	TRI-STATE Output off Current Low	$V_{CC} = V_{CCH}$ $V_{OZL} = 0.4V$			-20	μA

Note 1: All typicals are at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.

Note 2: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Switching Characteristics at $V_{CC} = 5V$ and $T_A = 25^{\circ}C$ (see Section 1 for Test Waveforms and output loading)

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Symbol	Parameter	R _L = 2 kΩ, C _L = 15 pF		Units
		Min	Max	
t _{PLH} t _{PHL}	Propagation Delay Data to Q		27 18	ns
t _{PLH} t _{PHL}	Propagation Delay LE to Q		36 25	ns
t _{PZH} t _{PZL}	TRI-STATE Enable Time OE to Q		20 25	ns
t _{PHZ} t _{PLZ}	TRI-STATE Enable Time OE to Q		20 25	ns
t _s (H) t _s (L)	Setup Time (High/Low) Data to LE	3 7		ns
t _h (H) t _h (L)	Hold Time (High/Low) Data to LE	3 7		ns
t _w (H)	Pulse Width (High) Data to LE	15		ns